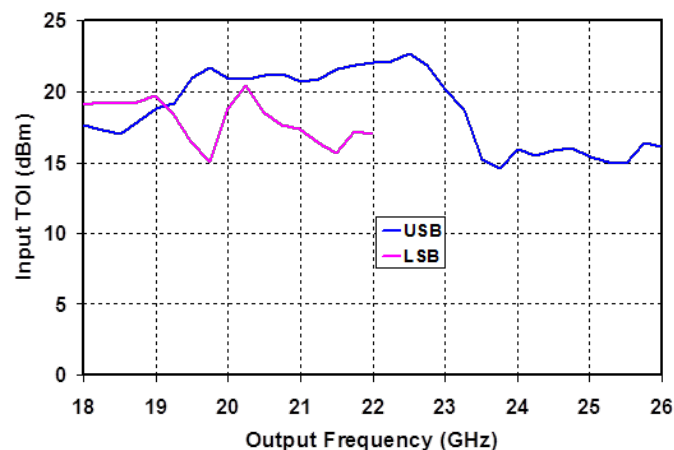
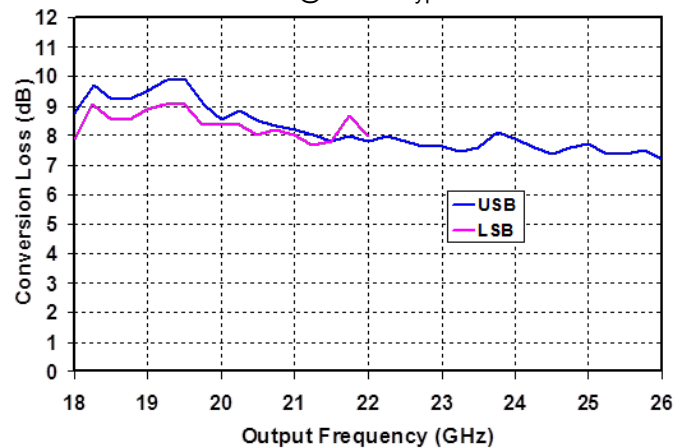


18 – 26 GHz Packaged Upconverting Mixer



Measured Performance

Bias conditions: $V_g = -0.9$ V, LO Input @ 19 dBm, IF = 2GHz @ -5 dBm Typical



Key Features

- RF Output Frequency Range: 18 - 26 GHz
- IF Input Frequency Range: 0.5 – 3 GHz
- Conversion Loss: 9 dB
- Input TOI: 18 dBm
- LO Input Power: 19 dBm
- Bias: $V_{mxr} = -0.9$ V
- Package Dimensions: 4 x 4 x 0.9 mm

Primary Applications

- Point-to-Point Radio
- K Band Sat-Com

Product Description

The TGC4402-SM upconverting mixer is designed to support a variety of millimeter wave applications including point-to-point digital radio and K band Sat-Com.

The TGC4402-SM provides 9 dB nominal conversion loss across 18-26 GHz. Typical LO input drive is 19 dBm across the band. The input IF Frequency is 0.5 – 3 GHz.

The TGC4402-SM requires only 2 off-chip components. Each device is 100% DC and RF tested on-wafer to ensure performance compliance. The device is available in chip form.

The TGC4402-SM has a protective surface passivation layer providing environmental robustness.

Lead-free and RoHS compliant

Datasheet subject to change without notice.

Table I
Absolute Maximum Ratings 1/

Symbol	Parameter	Value	Notes
V _{mxr}	Gate Supply Voltage Range	-5 - 0 V	
P _{in}	LO Input Continuous Wave Power	25 dBm	

1/ These ratings represent the maximum operable values for this device. Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device and / or affect device lifetime. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Table II
Recommended Operating Conditions

Symbol	Parameter	Value
V _{mxr}	Gate Voltage	-0.9 V

Table III
RF Characterization Table

Bias: V_{mxr} = -0.9 V, T_A = 25 °C ± 5°C

SYMBOL	PARAMETER	TEST CONDITIONS	NOMINAL	UNITS
F _{OUT}	RF Output Frequencies		18 - 26	GHz
F _{IF}	IF Input Frequency		0.5 - 3	GHz
F _{LO}	LO Input Frequency		16 - 26	GHz
P _{LO}	LO Input Power	f = 16 - 26 GHz	19	dBm
	Conversion Loss	f = 18 - 26 GHz	9	dB
ITOI	Input TOI	f = 18 - 26 GHz	18	dBm
	LO – RF Output Isolation	f = 16 - 26 GHz	40	dB
	Conversion Loss Temperature Coefficient	f = 16 - 26 GHz	-0.006	dB / °C

Table IV
Power Dissipation and Thermal Properties

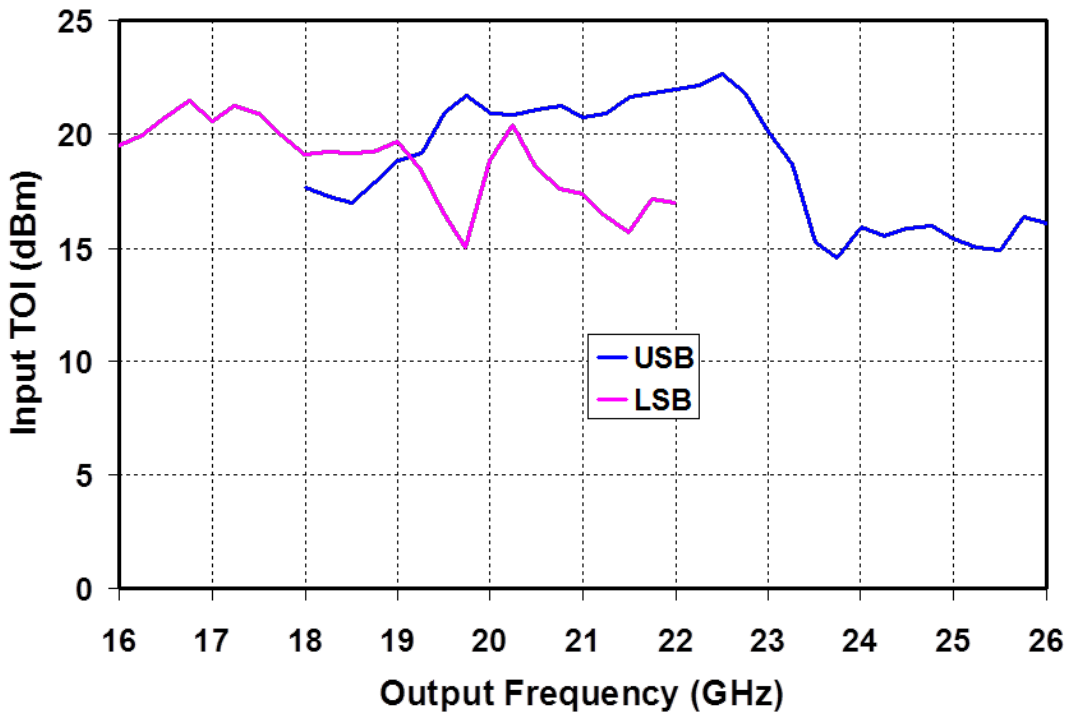
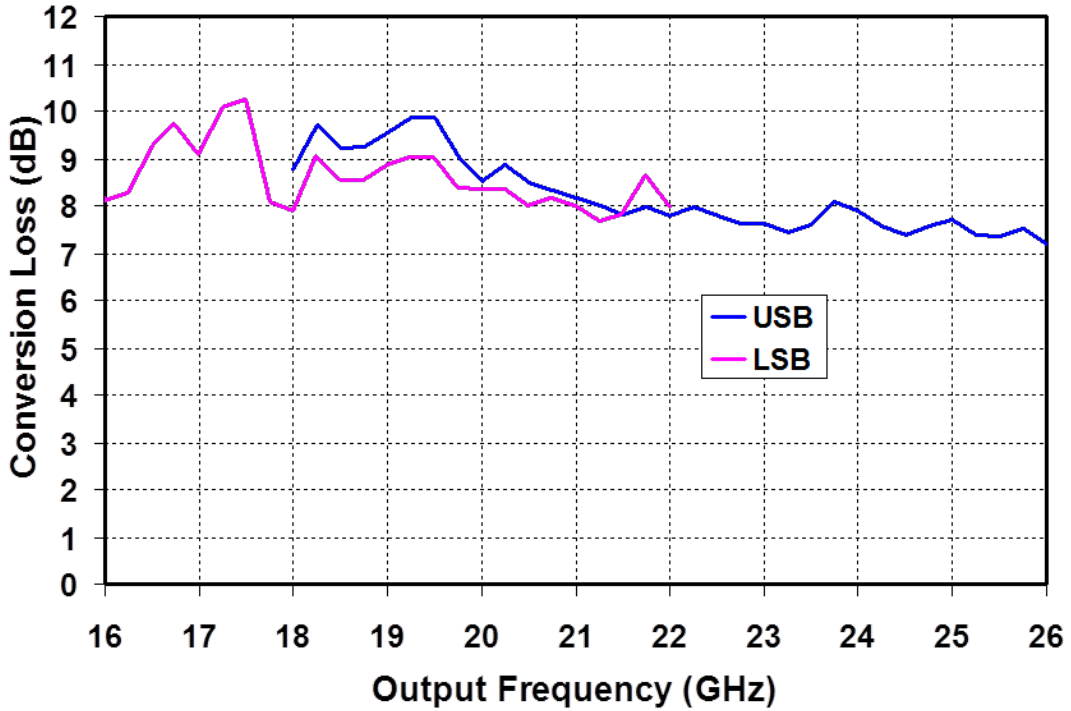
Parameter	Test Conditions	Value	Notes
Maximum Power Dissipation	Tbaseplate = 70 °C	Pd = 0.45 W Tchannel = 138 °C Tm = 1.0E+6 Hrs	1/ 2/
Thermal Resistance, θ_{jc}	LO input power is 17 dBm	θ_{jc} = 76 (°C/W) Tchannel = 121 °C Tm = >1E+6 Hrs	
Mounting Temperature	30 seconds	320 °C Max	
Storage Temperature		-65 to 150 °C	

- 1/ For a median life, Tm, of 1E+6 hours, power dissipation is limited to

$$Pd(max) = (TBD\text{ }^{\circ}C - Tbase\text{ }^{\circ}C) / \theta_{jc}.$$
- 2/ Channel operating temperature will directly affect the device median time to failure (MTTF). For maximum life, it is recommended that channel temperatures be maintained at the lowest possible levels.

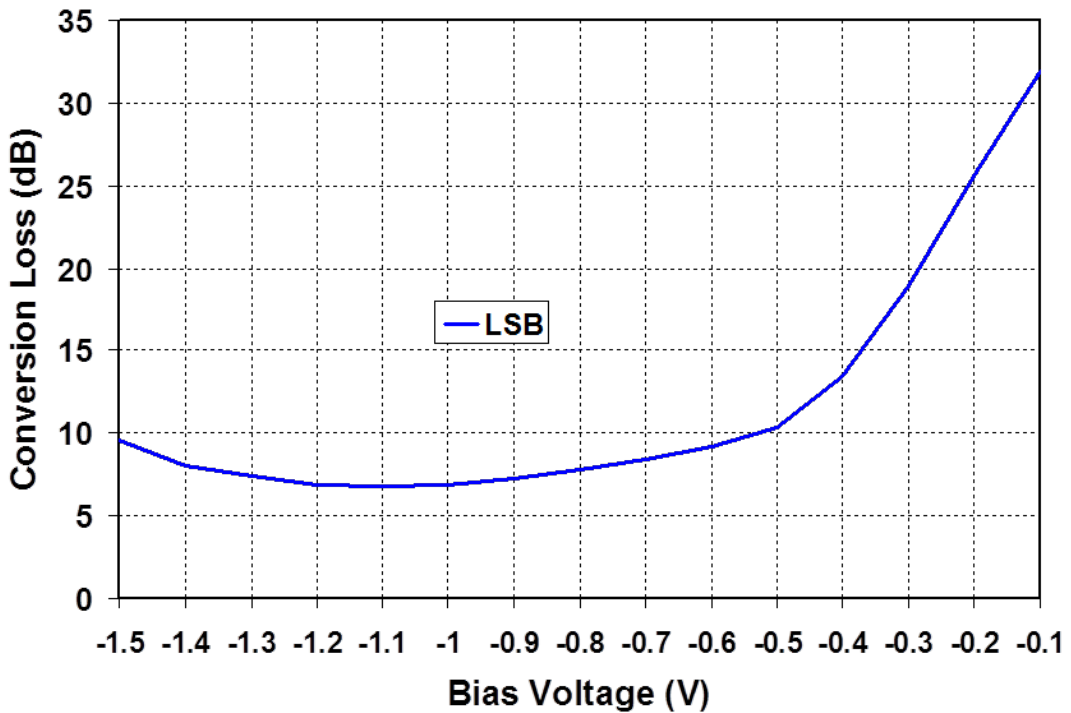
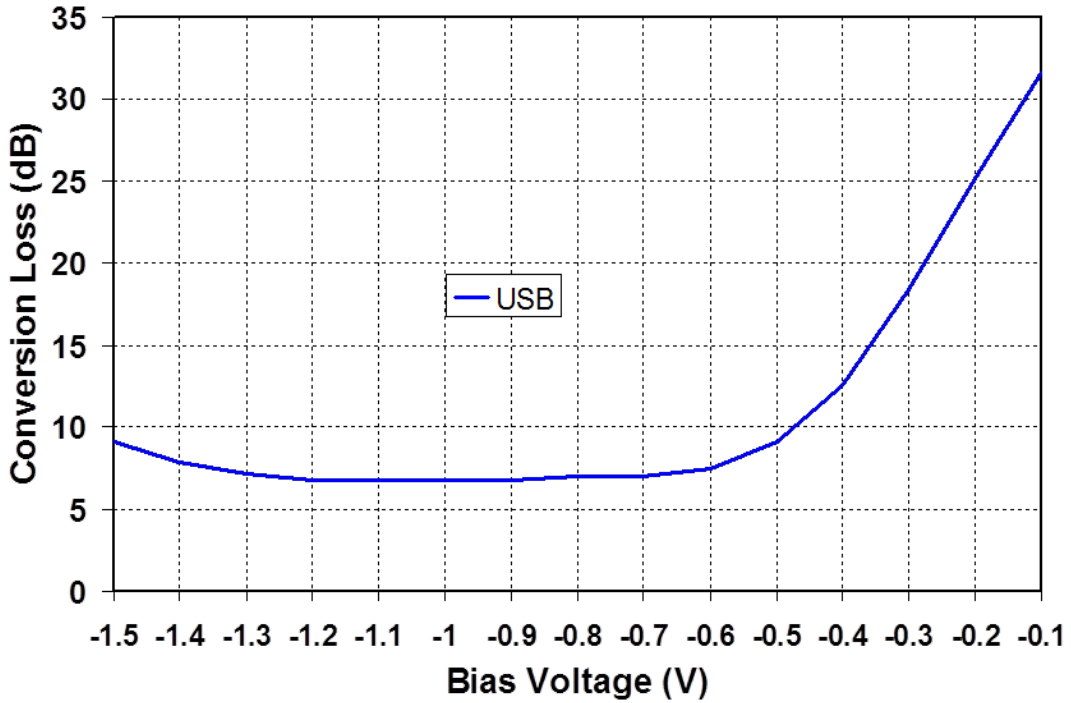
Measured Data

Bias conditions: $V_g = -0.9$ V, LO Input @ + 19 dBm, IF = 2 GHz @ -5 dBm Typical



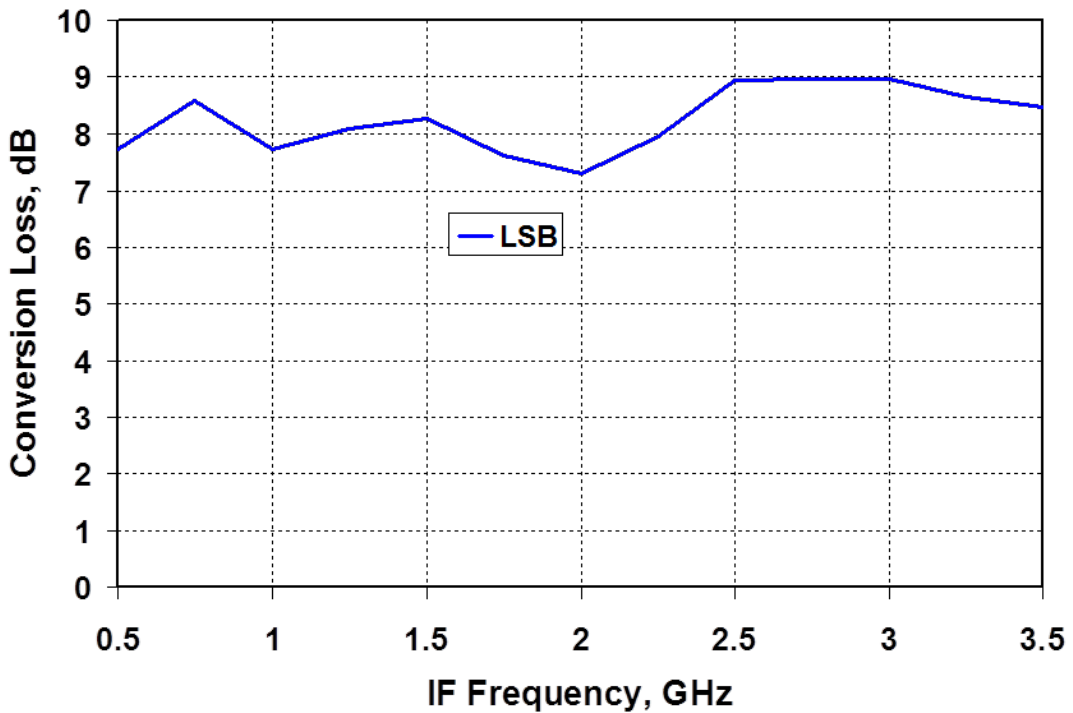
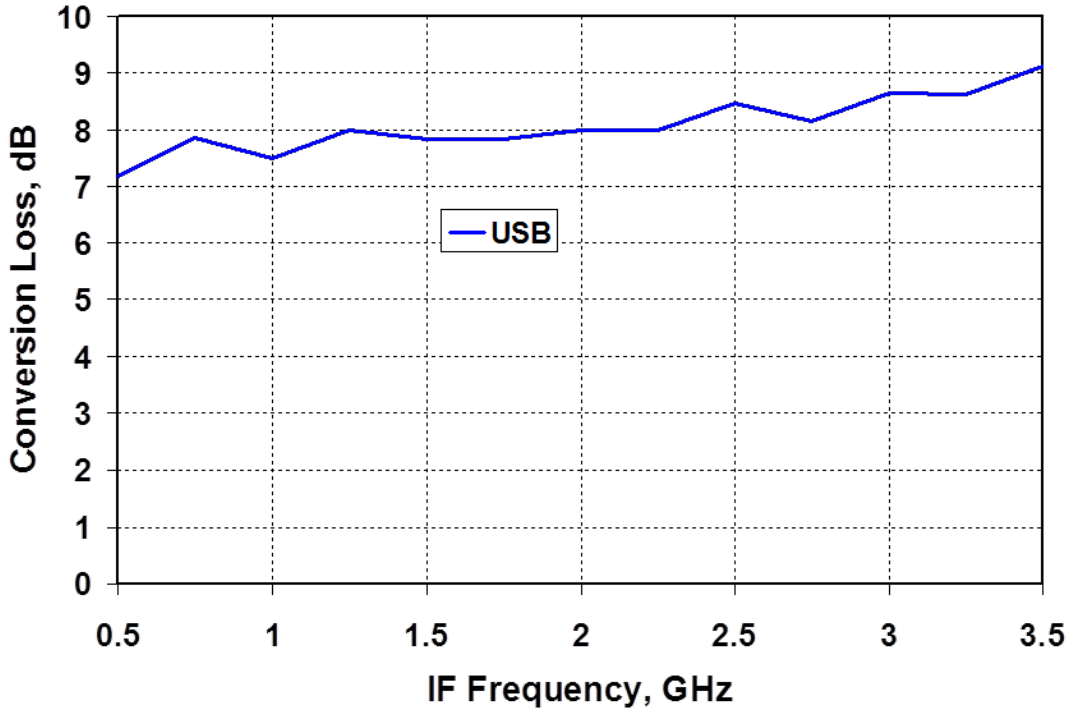
Measured Data

Bias conditions: $V_g = -0.9$ V, LO Input @ 20 GHz @ 19 dBm, IF = -5 dBm Typical



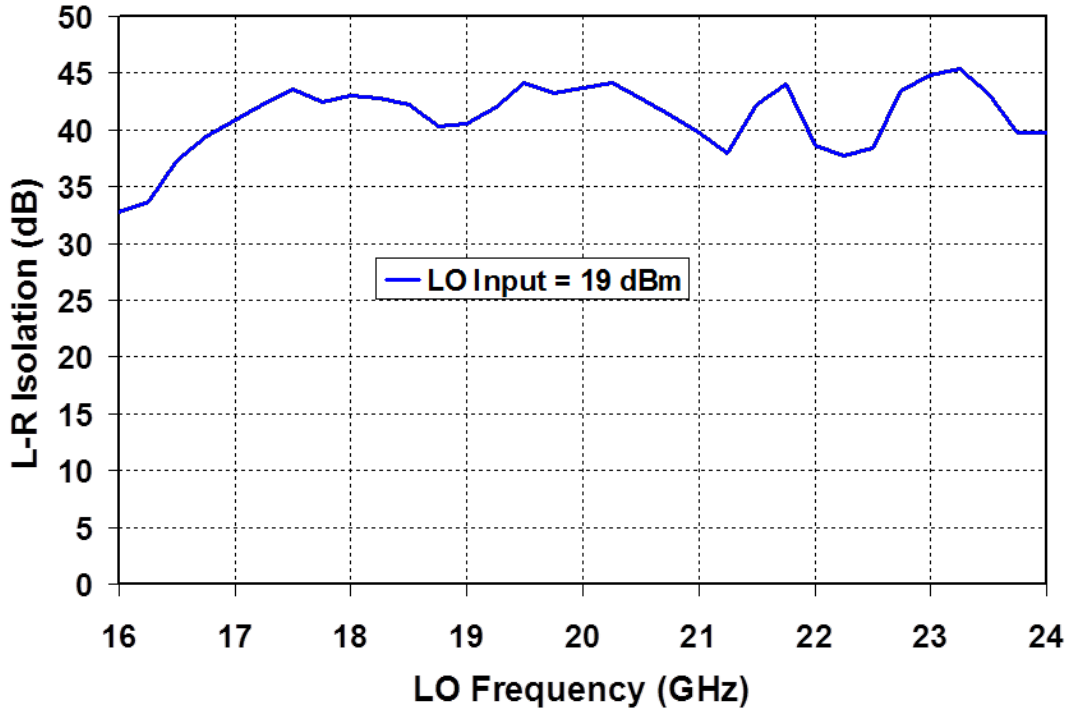
Measured Data

Bias conditions: $V_g = -0.9$ V, LO Input = 19 dBm, LO Freq = 20 GHz

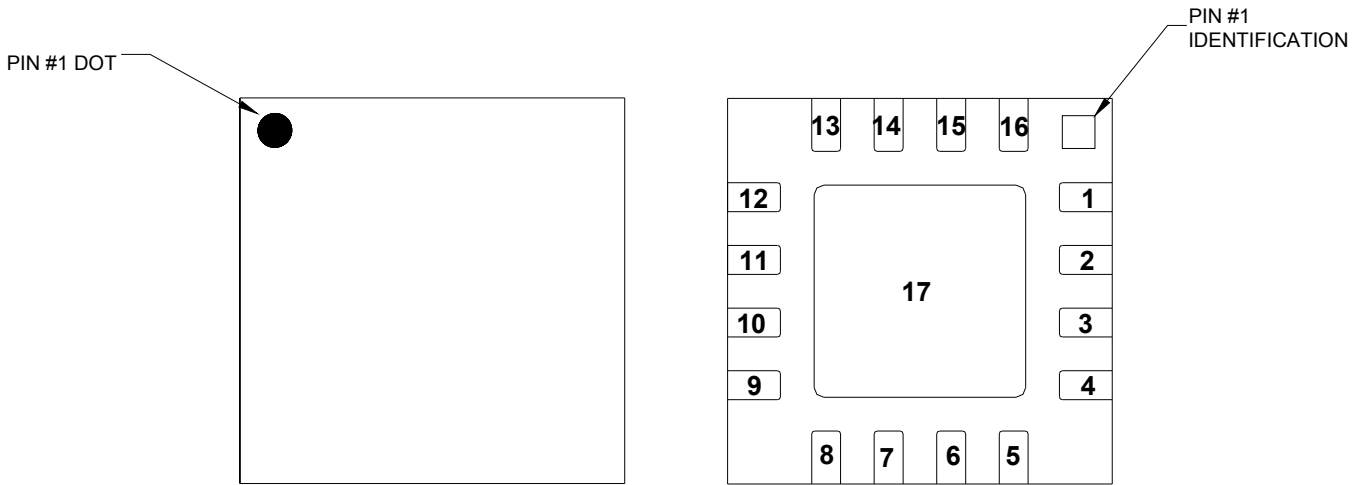


Measured Data

Bias conditions: $V_g = -0.9$ V, IF = 2 GHz @ -5 dBm Typical



Package Pinout

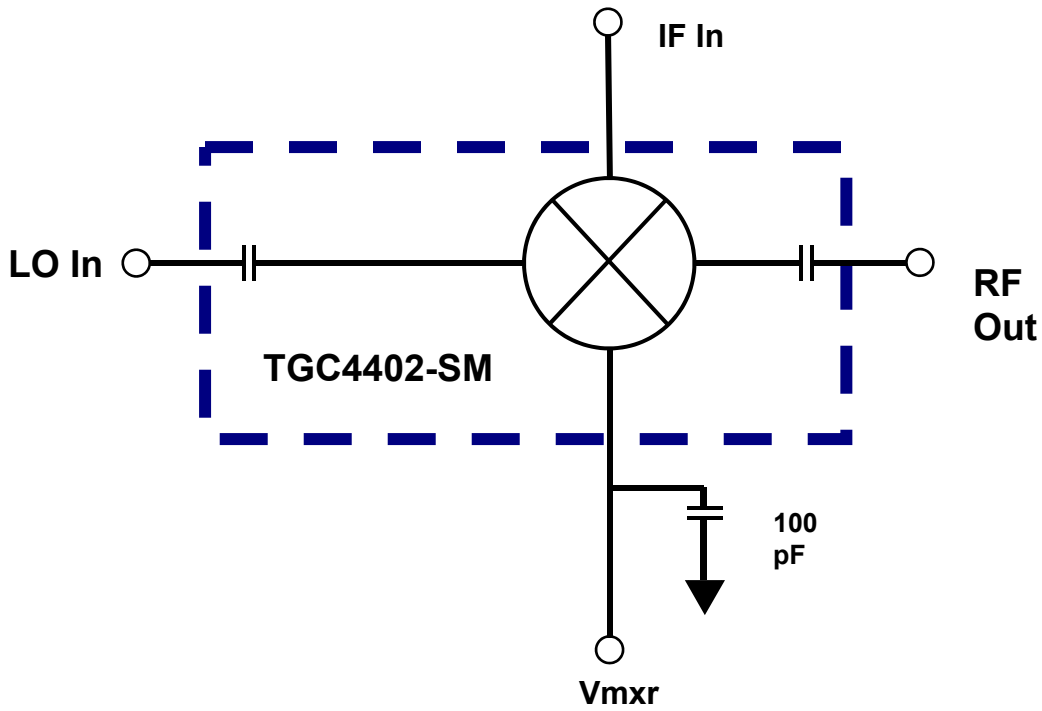


TOP VIEW

BOTTOM VIEW

Pin	Description
1, 3, 4, 6, 8, 9, 10, 11, 12, 14, 16	N/C
2	IF Input
5, 13	Vmxr
7	LO Input
15	RF Out
17	GND

Electrical Schematic



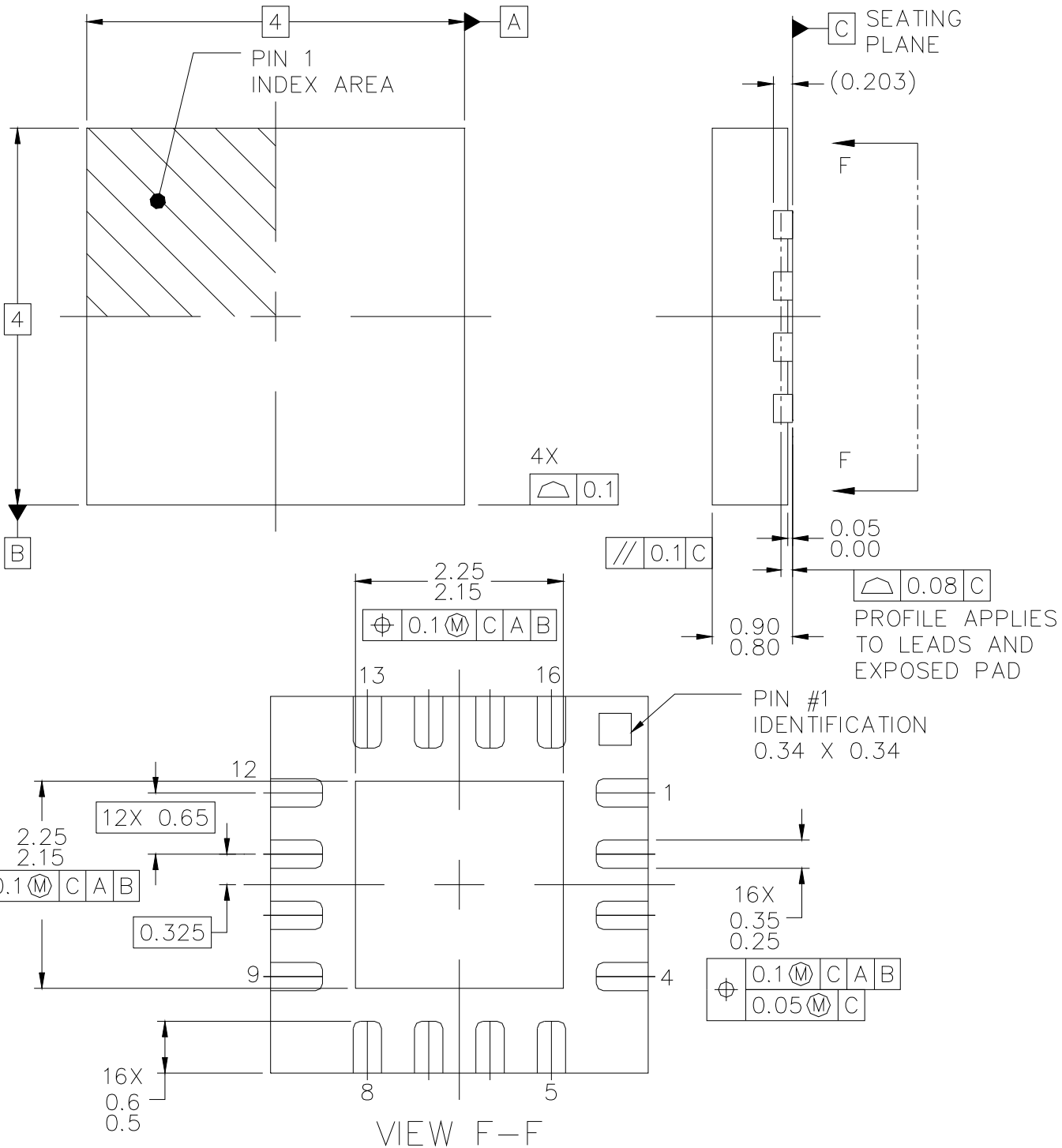
Bias Procedures

Bias-up Procedure

- Vmxr set to -0.9 V
- Apply signal to IF input
- Apply signal to LO input

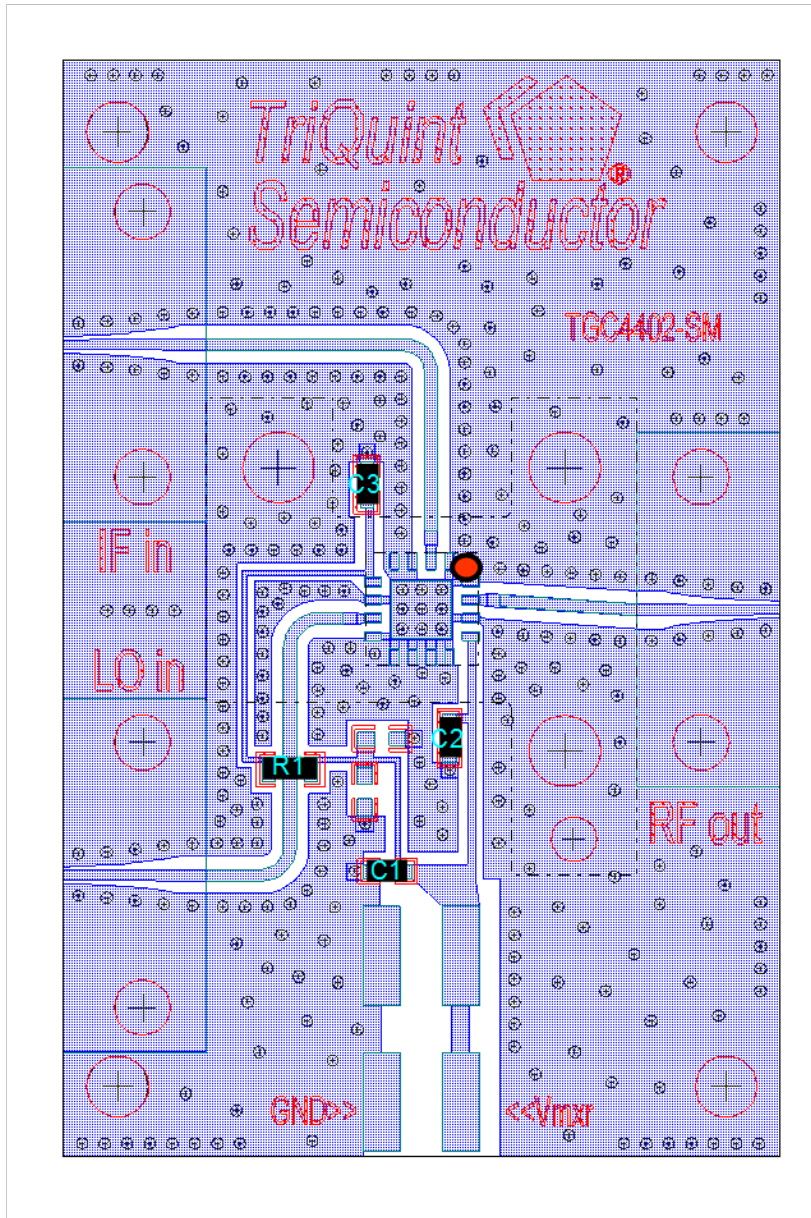
Bias-down Procedure

- Turn off IF and LO signals
- Set Vmxr to 0 V



GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

Recommended Assembly Diagram



Part	Description
C1 (optional)	1 uF Capacitor (0402)
C2, C3	100 pF Capacitor (0402)
R1	0 ohm Resistor (0603)

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.

Assembly Notes

Recommended Surface Mount Package Assembly

- Proper ESD precautions must be followed while handling packages.
- Clean the board with acetone. Rinse with alcohol. Allow the circuit to fully dry.
- TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.
- Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.
- Clean the assembly with alcohol.

Typical Solder Reflow Profiles

Reflow Profile	SnPb	Pb Free
Ramp-up Rate	3 °C/sec	3 °C/sec
Activation Time and Temperature	60 – 120 sec @ 140 – 160 °C	60 – 180 sec @ 150 – 200 °C
Time above Melting Point	60 – 150 sec	60 – 150 sec
Max Peak Temperature	240 °C	260 °C
Time within 5 °C of Peak Temperature	10 – 20 sec	10 – 20 sec
Ramp-down Rate	4 – 6 °C/sec	4 – 6 °C/sec

Ordering Information

Part	Package Style
TGC4402-SM	QFN 4x4 Surface Mount

GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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